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2019

Erdem, O., Gungor, K., Guzelturk, B., Tanriover, I., Sak, M., Olutas, M., . . . Demir, H. V. (2019). Orientation-controlled nonradiative energy transfer to colloidal nanoplatelets: engineering dipole orientation factor. Nano Letters, 19(7), 4297–4305. doi:10.1021/acs.nanolett.9b00681

https://hdl.handle.net/10356/140198

https://doi.org/10.1021/acs.nanolett.9b00681

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Orientation-controlled nonradiative energy transfer to colloidal nanoplatelets: Engineering dipole orientation factor

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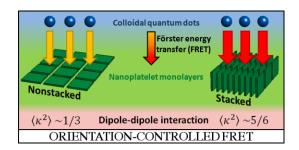
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ABSTRACT. We proposed and showed strongly orientation-controlled Förster resonance energy transfer (FRET) to highly anisotropic CdSe nanoplatelets (NPLs). For this purpose, we developed a liquid-air interface self-assembly technique specific to depositing a complete monolayer of NPLs only in a single desired orientation, either fully stacked (edge-up) or fully nonstacked (face-down), with near-unity surface coverage and across large areas over 20 cm². These NPL monolayers were employed as acceptors in an energy transfer working model system to pair with CdZnS/ZnS core/shell quantum dots (QDs) as donors. We found the resulting energy transfer from the QDs to be significantly accelerated (by up to 50%) to the edge-up NPL

monolayer compared to the face-down one. We revealed that this acceleration of FRET is accounted for by the enhancement of the dipole-dipole interaction factor between a QD-NPL pair (increased from 1/3 to 5/6) as well as the closer packing of NPLs with stacking. Also systematically studying the distance-dependence of FRET between QDs and NPL monolayers via varying their separation (d) with a dielectric spacer, we found out that the FRET rate scales with d^4 regardless of the specific NPL orientation. Our FRET model, which is based on the original Förster's theory, computes the FRET efficiencies in excellent agreement with our experimental results and explains well the enhancement of FRET to NPLs with stacking. These findings indicate that the geometrical orientation of NPLs and thereby their dipole interaction strength can be exploited as an additional degree of freedom to control and tune the energy transfer rate.

KEYWORDS. semiconductor nanocrystals, nanoplatelets, liquid-air interface self-assembly, stacking, energy transfer, dipole orientation

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Förster (or fluorescence) resonance energy transfer (FRET) is the nonradiative transfer of excitation energy from one fluorophore (donor) to another one (acceptor), which is induced by near-field interactions of oscillating dipoles.^{1,2} Although initial studies on FRET focused on fluorescent dyes and proteins, FRET has gained further attraction after the introduction of

colloidal nanocrystals (NCs).^{3–11} Being an extremely distance-sensitive process, FRET involving NCs is used in a variety of applications including light-harvesting⁵, optoelectronic structures⁷ and biosensing.^{12,13}

Apart from the donor-acceptor distance, the strength of FRET depends on a number of parameters including the spectral overlap of the donor and acceptor and the radiative emission rate of the donor as well as the relative orientation of donor and acceptor dipoles.¹⁴ The last parameter, commonly denoted as κ^2 , is especially important when either the donor or acceptor fluorophore has an anisotropic dipole state. In the case that the dipole states of both fluorophores rotate freely in three dimensions in an ensemble, $\langle \kappa^2 \rangle$ equals 2/3, which is the average value for the dipole orientation factor.¹ However, for dipoles confined along one or two dimensions, or whose rotation is limited by any other means, this factor is expected to be different.¹⁴ Therefore, if the orientation of all of the anisotropic donor or acceptor species in an ensemble is controlled, we propose that the strength of FRET in semiconductor NC ensembles can be modified via tuning the average dipole-dipole interaction coefficient, $\langle \kappa^2 \rangle$, which would serve as another degree of freedom to control FRET. However, the control of $\langle \kappa^2 \rangle$ in NCs over macroscopic areas has remained elusive to date.

Here, to control the dipole interaction and investigate its effect on FRET, we employed colloidal semiconductor nanoplatelets (NPLs) as acceptors. As the last class of solution-processed semiconductor NCs with atomically flat surfaces and vertical-tight quantum confinement of few atomic monolayers, these free-standing NPLs make quasi two-dimensional quantum wells with a very small thickness of 1-2 nm and lateral dimensions ranging from several to 100s nm. Thus NPLs feature intrinsically high anisotropy, because of which their transition dipole state near the band edge is mostly confined within the NPL plane. 17

Furthermore, unlike other 2D materials such as epitaxially grown quantum wells and transition metal dichalcogenides, the colloidal nature of NPLs provides the ability to deposit them in an orientation of one's choice in their thin-films.^{17–19} This feature of NPLs, along with their unusually large extinction coefficient, makes them attractive materials as FRET acceptors with the capability of dipole interaction control.

NPLs in an ensemble might adopt one of two orientations. The former is regarded as nonstacked, or face-down, 17,22 where NPLs lie flat on a substrate with their lateral surfaces being parallel to it. In the latter, i.e., stacked or edge-up orientation, ^{17,23} NPLs stand vertically on their peripheral surfaces, face each other instead of facing down and can form long one-dimensional NPL chains. Stacking of NPLs has been investigated on several previous reports of our group and others on various aspects. It was previously shown that stacking modifies the excitonic dynamics in NPLs through ultra-fast intra-stack energy transfer. 19,24,25 Polarized emission out of NPL stacks has been reported on both solid²³ and flexible²⁶ films. Stacking in NPLs was also utilized to observe their orientation-dependent emission patterns.¹⁷ These previous reports confirm that optical properties of NPLs are strongly modified with their orientation. However, with conventional methods of sample preparation such as drop-casting or spin-coating, observing NPL ensembles with mixed orientation is quite possible. 18,21,27,28 To address this problem, liquidair interface self-assembly has been employed, which enabled orientation control of plateletshaped NCs. 17,29 With this technique, nanoplates in a single orientation could be deposited in film, either as multilayers²⁹ or as small domains with relatively low coverage on the surface.¹⁷ However, to the best of our knowledge, a uniform deposition of NPLs as a single monolayer in one particular orientation over large areas has not yet been achieved, which limits the effective utilization of anisotropy in these NPLs.

In this work, we developed a method of NPL self-assembly at a liquid-air interface, through which we successfully deposited CdSe NPLs as a single monolayer in the desired orientation over a solid substrate. The resulting self-assembled NPLs are either fully nonstacked or fully stacked. Furthermore, their surface coverage is close to unity in both cases, with domain sizes that can be as large as the area of the substrate. In our working model system, we used blue-emitting CdZnS/ZnS core/shell QDs as the donor species on top of these NPLs and studied the strength and distance dependence of FRET between them. The measured rate of FRET from QDs to NPLs is significantly faster when using the stacked NPL monolayer compared to the nonstacked one. We found in the case of stacking that, along with the increased packing density, the enhanced dipole-dipole interaction of the stacked NPLs with the QDs accelerates FRET substantially.

We also systematically studied the distance (d) dependence of FRET to the NPLs by placing Al₂O₃ as a separating layer in between the QDs and NPL monolayers and tuning its thickness, and observed that the FRET rate exhibits a d^4 -dependence, as would be expected for a plane of acceptors. To calculate the FRET rates in the cases of using the nonstacked vs. stacked NPL acceptors, we utilized Förster's original theory of nonradiative energy transfer. In doing so, we have taken into account the uniform density of exciton states across the NPL as well as the dipole-dipole interaction strength being a function of both the position and orientation of the acceptor dipole. Our computations in both cases show excellent agreement with the FRET rates extracted from time-correlated single photon counting experiments. This work demonstrates for the first time that the orientation of these anisotropic NPLs can be controlled over large areas and used for tuning the strength of the energy transfer by controlling the orientation of the acceptor dipole.

Results and Discussion. CdSe NPLs having 4 monolayer (ML) atomic thickness, and monodisperse CdZnS/ZnS QDs were synthesized using previously reported recipes with slight modifications (see Methods). Transmission electron microscopy (TEM) image of the NPLs is depicted in **Figure 1**. The NPLs have square-like surfaces with a side length of 14.4 ± 2.0 nm as measured from the TEM images. A mixture of nonstacked and stacked NPLs with different orientations with respect to the TEM grid is visible in the image, which is typically found in NPL solid films.

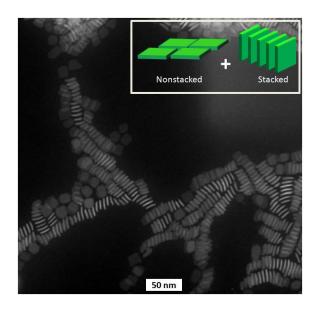


Figure 1. High-angle annular dark-field scanning transmission electron microscopy (HAADF-STEM) image of 4 ML CdSe NPLs. Inset schematically shows the orientation of nonstacked (face-down) and stacked (edge-up) NPLs in three dimensions with the imaged facets highlighted in light green.

For the construction of a NPL monolayer only of a single desired orientation, we developed a liquid-air interface self-assembly technique that enabled us to deposit a large-area CdSe NPL monolayer with near-unity surface coverage. Previously, liquid-air interface self-assembly was

used to deposit colloidal metal nanoparticles^{32,33} and semiconductor QDs.³⁴ Also, Diroll *et al.* demonstrated self-assembly of nanorod (NR) superlattices by using different subphases to control NR orientation.³⁵ The interaction between the subphase and the NC and its solvent was also utilized by Paik *et al.* for GdF₃ nanoplates to create multiple layers of "lamellar" (stacked) or "columnar" (nonstacked) assemblies of these nanoplates with full surface coverage over large area.²⁹ More recently, Gao *et al.* studied the emission patterns of self-assembled CdSe NPL films created *via* liquid-air interface self-assembly.¹⁷ In this previous study, although the NPLs exhibited a uniform orientation in film with domains as large as several tens of μm, these domains were separated with gaps having no NPL coverage. In the present study of ours, different than previous reports, the orientation-controlled NPLs are deposited both as a single monolayer only and with full surface coverage over areas that can be as large as tens of cm².

Our self-assembly procedure is illustrated in **Figure 2**a. Substrates (silicon wafers containing 25 nm thick Al₂O₃ films pre-deposited on top) are initially placed inside a subphase contained in a teflon well. The subphase is denser than the solvent of the NPLs (hexane) and has high enough polarity to ensure its immiscibility with the NPL solution. In our approach, exploiting different surface tensions and polarities of our subphases to dictate the NPL orientation on the interface, ^{29,35} we identified acetonitrile (ACN) as the subphase that allows to obtain a nonstacked self-assembled monolayer and ethylene glycol (EG) that yields a stacked one. Once dropped onto the subphase, the NPL solution spreads around the surface of the liquid interface. The NPL solution is then let dry, after which the NPLs on the interface form a uniform membrane. To transfer these NPLs onto substrates, the subphase is slowly drained through a needle and the residual subphase between the substrates and the NPL membrane is evaporated.

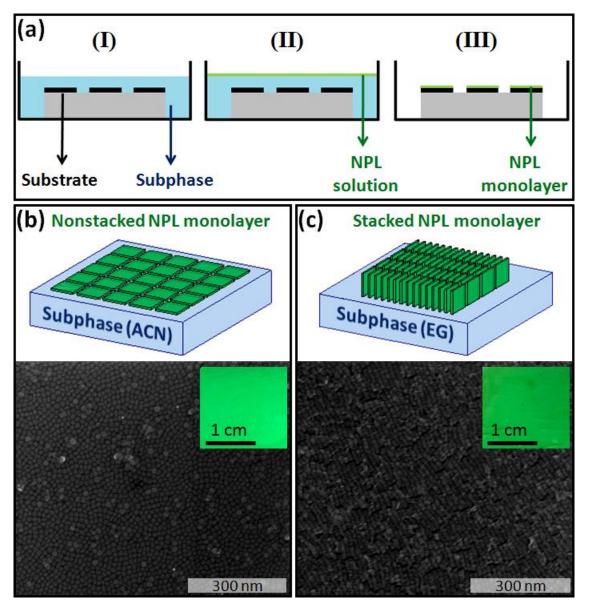


Figure 2. (a) Liquid-air interface self-assembly procedure: (I) Blank substrates are placed inside the subphase. (II) NPL solution is poured onto the subphase and is then let dry. (III) The subphase is subsequently drained after the evaporation of the NPL solution. Finally, the residual subphase on the substrates is evaporated. NPL orientation on the liquid-air interface depends on the subphase. Schematic representation of NPL monolayers (b) on acetonitrile (ACN) and (c) on ethylene glycol (EG), along with scanning electron microscopy (SEM) images of these films after being transferred to a solid substrate. The scale bars of the SEM images are 300 nm. ACN

results in nonstacked self-assembly whereas EG results in stack formation. Insets in the SEM images show real-colour fluorescence images of the resulting monolayer assemblies on wafers of thermal oxide with scale bars of 1 cm.

The scanning electron microscopy (SEM) images of the resulting self-assembly films are displayed in **Figure 2**b and **Figure 2**c. It can be seen that the self-assembled NPLs deposited using ACN are in a fully nonstacked orientation. Furthermore, apart from minor irregularities, the deposited NPLs form a full monolayer and are as closely packed as possible in nonstacked configuration with rare small gaps between them in the film (see Figure S2). The stacked NPLs were also deposited uniformly onto the film as a monolayer with no apparent aggregate or multilayer formation (see Figure S3). The stacks appear to be partially aligned within grains of few µm² (see Figure S3a). This alignment can be further improved in principle such that all of the stacked chains in the film are aligned in the same direction. This might result in a highly polarized emitting monolayer. The full alignment of the chains throughout the whole substrate, however, is out of the scope of this current study and will be investigated in a future work.

By controlling the amount of NPL solution to be dropped, we are able to create domains with controlled NPL orientation over areas of at least a few mm². Although this domain size is sufficient for ensemble measurements, it can be extended up to tens of cm² with the assistance of a surfactant (silicone oil)³³ to further compress the monolayer NPL membrane on the liquid-air interface and reduce the crack formation during the transfer process as well as the voids. As an exemplary demonstration, 2-inch wafers of silicon oxide thermally grown on Si, which have an area of ~20 cm², have been deposited with a monolayer of nonstacked or stacked NPLs (see **Figure 2**b, c insets, also Figure S4). To achieve this, we carefully controlled the concentration and the amount of NPL solution to be dropped onto the subphase such that when fully spread

over the subphase, the NPLs cover virtually the whole surface of the liquid-air interface. For that, the concentration of NPL solution was estimated using the work of Yeltik *et al.* ²⁰

To develop a deeper understanding on how the orientation of these NPLs affects their excitonic properties, we employed the self-assembled NPLs as acceptors in an energy transfer model system. Specifically, we hypothesize that the rate of FRET from isotropic QDs to anisotropic NPLs should be modified because of the changing dipole-dipole coupling strength between a QD-NPL pair for different NPL orientations. CdZnS/ZnS core/graded shell blue-emitting QDs dispersed in toluene were spin-coated directly onto the self-assembled NPL films. The SEM images of the resulting QD films are shown on nonstacked NPLs in Figure 3a and on stacked NPLs in Figure 3b. QDs are seen to have a sub-monolayer coverage on top of the NPLs, which ensures that all of the deposited QDs are equally distant to the NPL plane, and hence are coupled to the NPL film to the same extent (otherwise with a QD film thicker than one monolayer, some of the QDs would remain slightly further away to the NPLs, and FRET from those QDs would be weaker than from the QDs directly over the NPL monolayer). Since there is a significant spectral overlap between the PL emission of QDs and the absorption of the NPLs (Figure 3c), energy transfer from QDs to NPLs is expected to take place. To calculate the rate of the energy transfer, we collected the PL decays of QDs when they are deposited on top of nonstacked NPLs and stacked NPLs and compared these two decays with the decay of only-QD film (with no acceptor). Here, the decay rate of donor QDs in the presence of acceptors is modified according to

$$\frac{1}{\tau_{DA}} = \frac{1}{\tau_D} + k_T \tag{1}$$

where τ_D (τ_{DA}) is the PL lifetime of donor in the absence (presence) of the acceptors and k_T is the rate of energy transfer from the donor to the acceptor.

The PL decays of the QDs alone, the QDs on top of the nonstacked NPLs and the QDs on top of the stacked NPLs are plotted in **Figure 3**d. The amplitude-averaged lifetime of only QDs is 4.72 \pm 0.36 ns, whereas in the presence of the nonstacked and stacked acceptors, the average QD lifetime reduces to 1.08 \pm 0.09 and 0.79 \pm 0.07 ns, respectively. Using Equation 1, these lifetimes yield FRET at the rates of 0.71 ns⁻¹ to the nonstacked NPLs and 1.05 ns⁻¹ to the stacked NPLs. Hence, the rate of FRET to the stacked NPL monolayer is ~50% faster than to the nonstacked one. Since our domain sizes are much larger than the spot size of the excitation laser (~100 μ m), we can assert that all the excited QDs are coupled to the nearby NPLs and hence undergo FRET, and that there is no contribution of uncoupled QDs to the PL decay in either case.

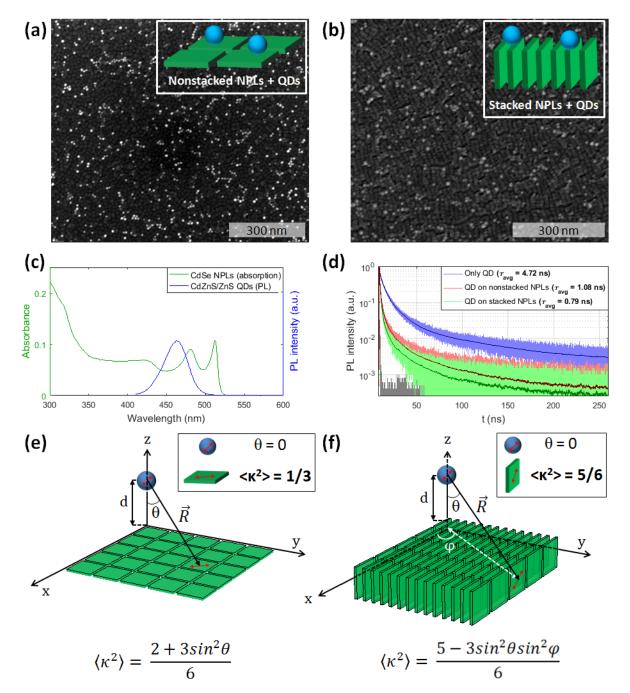


Figure 3. SEM images of CdZnS/ZnS QDs on (a) the nonstacked NPLs and (b) the stacked NPLs. (c) Absorbance spectrum of NPLs (green) and PL spectrum of QDs (blue). (d) PL decays of the QDs in the absence of NPLs (blue), on top of the nonstacked NPLs (red), and on top of the stacked NPLs (green), along with their multiexponential fits convolved with the instrument response function (gray). Average dipole-dipole interaction coefficient of a QD and an NPL

monolayer when the NPLs are (e) nonstacked and (f) stacked, as a function of the dipole's position. Insets show the value of $<\kappa^2>$ for a pair of the QD and the nearest NPL to it.

To account for the difference in the rate of FRET to the stacked and nonstacked NPL monolayers, we make use of Förster's theory of nonradiative energy transfer. It is also possible to account for the observed difference in the emission kinetics and energy transfer rates through Purcell effect for emitters near planarly layered media, as was previously reported; 36,37 here we limit our discussion to Förster model, which allows to explain anisotropic dipole-dipole interactions present in our case. Accordingly, the rate of energy transfer from a donor to an acceptor is proportional to the average dipole-dipole interaction coefficient $<\kappa^2>$ for this pair of the donor and acceptor. When both the donor and acceptor dipoles are isotropic, $<\kappa^2>$ is taken to be 2/3. In our case, however, the acceptor dipole is mostly confined within the NPL plane, which requires $<\kappa^2>$ to be evaluated accordingly. For an in-plane dipole of a face-down NPL, as depicted in **Figure 3**e, the average of the QD-NPL dipole interaction coefficient is calculated as (see Supporting Information).

$$\langle \kappa^2 \rangle = \frac{2 + 3\sin^2\theta}{6} \tag{2}$$

where θ is the angle between the surface normal of the NPL plane and the position vector \vec{R} extending from the donor dipole to the acceptor dipole (see **Figure 3**e). Among the NPLs on the acceptor plane, FRET will be the strongest to the NPL that is the nearest to the QD, for which θ is close to zero. Hence, $\langle \kappa^2 \rangle$ is approximately 1/3 for a QD and the closest nonstacked NPL to it. On the other hand, for the stacked monolayer of NPLs (see Supporting Information),

$$\langle \kappa^2 \rangle = \frac{5 - 3\sin^2\theta \sin^2\phi}{6} \tag{3}$$

where ϕ is the angle between the x-axis and the projection of \vec{R} onto the xy-plane (see **Figure 3f**). Here, it is assumed that NPL stacks are aligned along one of the lateral axes, y. This assumption can be justified by noting the local alignment of the stacks as seen in **Figure 2c** and **Figure 3b** (and Figure S3a). As a result, for a pair of the QD and the NPL closest to it in this case, $\langle \kappa^2 \rangle = 5/6$. Therefore, the dipole-dipole interaction between a QD and an NPL is strongly enhanced when NPLs are stacked, compared to the case in which NPLs are nonstacked.

Another difference between the stacked and nonstacked NPL monolayers is that stacking allows a much denser packing of NPLs. Taking into account the lateral area of NPLs, the length of oleate surfactants, 1.8 nm, 38 attached to the NPL surfaces, and the center-to-center distance of 4.3 nm between neighbouring 4 ML CdSe NPLs in a stack, 19 the surface density of NPLs has been estimated to be 3.09 × 10³ µm⁻² for the nonstacked NPLs and 1.29 × 10⁴ µm⁻² for the stacked NPLs. Therefore, there is almost a 4-fold increase in packing density with the stacking of NPLs. This means that more NPLs can be in close proximity of a QD in the case of stacking. Moreover, the dipole interaction will be stronger for these NPLs compared to the nonstacked ones, as discussed above. Combining these two factors, it can be expected for the strength of FRET to increase with stacking of NPLs.

To develop a quantitative analysis on how FRET is affected by the NPL orientation, we investigated the strength of FRET by varying the distance between the QDs and the NPL monolayer in a systematic way. For this purpose, we added a spacer of Al₂O₃ *via* atomic layer deposition, whose film thickness is swept from 1 to 15 nm, between the QDs and self-assembled NPL monolayer. The overall structure is schematically depicted in **Figure 4**a for the nonstacked NPLs and in **Figure 4**b for the stacked NPLs. There is also a bottom Al₂O₃ film, which is deposited directly on Si substrate to avoid energy transfer from the QDs to the Si wafer.³⁹⁻⁴¹

NPLs were laid down via the described self-assembly procedure. Using our setup, which is capable of depositing up to twelve 1×1 cm² substrates simultaneously (see Figure S1), a set of NPL films (i.e. fully nonstacked or fully stacked) were deposited at once to ensure all the NPL films are prepared under the same experimental conditions. Diluted solution of QDs was spin coated onto the Al₂O₃ spacer or directly onto the NPL monolayer (no spacer case). The PL decays of QDs are plotted in Figure 4c and Figure 4d for the QDs over the nonstacked and stacked NPLs, respectively. The decays of films without a spacer, displayed in Figure 3d, are also added here, labeled as "0 nm Al₂O₃" in the legend. It can be seen that as the spacer thickness decreases, the decays are progressively accelerated, indicating FRET growing increasingly stronger. The amplitude-averaged PL lifetimes as a function of the Al₂O₃ film thickness are plotted in Figure 4e. The PL lifetimes converge to that of only donor with increasing spacer thickness as expected. The corresponding rates of FRET are calculated using Equation 1 and presented in Figure 4f. For all the spacer thicknesses, FRET is stronger in the case of stacked NPLs. Finally, Figure 4g depicts the efficiency of FRET from the QDs to the nonstacked and stacked NPL monolayers. The FRET efficiency is given by

$$\eta = \frac{1}{1 + \left(\frac{d}{d_0}\right)^p} \tag{4}$$

where d_0 is the Förster distance at which the efficiency is 50%, and p is the exponent indicating the dependence of FRET rate on the distance; it is 6 for a pair of point-like donor and acceptor and is lower for higher acceptor dimensionalities. The effective distance d here is defined from the center of the QD to the plane of acceptors (see **Figure 3e**, f), as is commonly used in hybrid FRET systems employing QDs. The FRET efficiency was calculated from the lifetime data using $\eta = 1 - \tau_{DA}/\tau_D$ and fit to Equation 4 to estimate the Förster distance as well as the distance-dependence of the FRET. For the nonstacked NPL monolayer, the best fit parameters

are $d_0 = 11.2$ nm and p = 3.78, whereas for the stacked NPL monolayer, they are $d_0 = 12.1$ nm and p = 4.08. Therefore, the distance dependence in both cases is close to d^{-4} as expected for FRET to the 2D materials^{44–46} or to plane of acceptors.^{9,47}

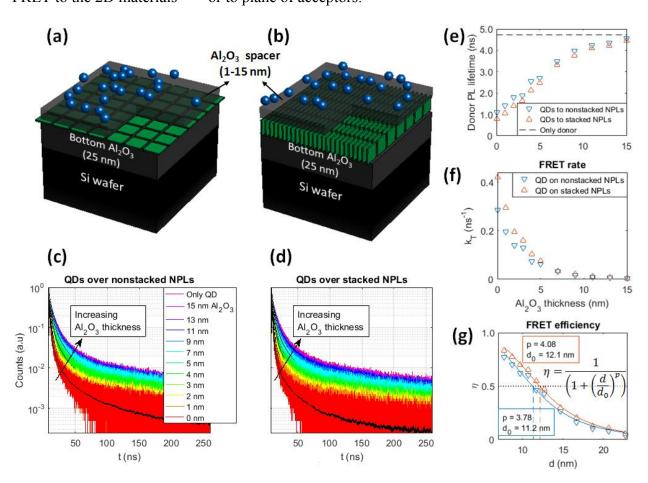


Figure 4. Film structure for distance-dependent FRET from the QDs to (a) the nonstacked NPLs and (b) the stacked NPLs. The spacer thickness is varied from 1 to 15 nm. PL decays of QDs over (c) the nonstacked NPLs and (d) the stacked NPLs for tuned spacer thicknesses. The black curves are multiexponential fits to PL decays convolved with the instrument response function. (e) The resulting PL lifetimes of QDs and (f) extracted rates of FRET to the nonstacked (blue down triangles) and the stacked NPLs (orange up triangles). (g) FRET efficiencies as a function of the donor-acceptor distance along with their numerical fits to the FRET efficiency formula in the inset (Equation 4). The data captures the d^4 behaviour in general for both the nonstacked and

stacked NPLs. The horizontal dashed lines indicate the Förster distances for FRET to the nonstacked (blue) and stacked (orange) NPLs.

To calculate the FRET rate from the QDs to the nonstacked or stacked NPLs, we make use of Förster's treatment of energy transfer. Accordingly, the rate of energy transfer k_T from a donor species to an acceptor one is 14

$$k_T = \frac{\langle \kappa^2 \rangle \cdot QY}{r^6 \tau_D} \frac{9ln10}{128\pi^5 Nn^4} J \tag{5}$$

where QY is the PL quantum yield of the donor species in the absence of acceptors, r is the distance between the donor and acceptor, N is Avogadro's number, n is the refractive index of the medium and J is the spectral overlap between the emission of the donor and absorbance of the acceptor, given by

$$J = \int_{0}^{\infty} F_{D}(\lambda) \varepsilon_{A}(\lambda) \lambda^{4} d\lambda \tag{6}$$

Here $F_D(\lambda)$ is the normalized PL intensity spectrum and $\varepsilon_A(\lambda)$ is the wavelength-dependent molar extinction coefficient of the NPLs. The QY of our QDs were measured to be 65% in film. n = 1.72 was used as the refractive index of the medium. For FRET systems where the size of the donor and acceptor are much smaller than their separation, r can be taken as the center-to-center distance between the donor and the acceptor. However, this is not the case with our NPLs, as their size is comparable to the QD-NPL separation. Assuming the dipole is centered inside the NPL is therefore not very suitable. Instead, we use an approach that has been utilized by Shafran $et\ al.$ previously for FRET from QDs to carbon nanotubes, where they proposed a stochastic model in which the probability of FRET to a particular point on a carbon nanotube is proportional to the FRET rate calculated by Equation 5 and calculated the total rate of FRET to

anywhere on the carbon nanotube accordingly.⁴⁸ We approximate the NPLs as infinitesimally thin quantum wells with lateral dimensions much larger than the exciton Bohr radius, in which case the density of states available for energy transfer would be uniformly distributed across the NPL cross-sectional area. Then, the rate of energy transfer to a single NPL is:

$$k_{T,NPL} = \frac{1}{A} \iint_{A} k_{T|\vec{r}'} dA' \tag{7}$$

where $k_{T|\vec{r}'}$ is the FRET rate for an acceptor dipole state localized at \vec{r}' as calculated using Equation 5. The dipole-dipole distance for a particular position \vec{r}' on the NPL is $r = |\vec{R}_0 + \vec{r}'|$ where R_0 is the center-to-center distance between the donor and the acceptor NCs (see **Figure 5**a and **Figure 5**b). Similarly, $\langle \kappa^2 \rangle$ will depend on \vec{r}' through Equation 2 for the nonstacked NPL ensemble and Equation 3 for the stacked one. For a particular NPL, the integral in Equation 7 is taken over the NPL cross-sectional area. The total FRET rate to the NPL monolayer is then found by adding up the FRET rates from a QD to all the NPLs in the monolayer. The FRET rates to the nonstacked and stacked NPL monolayers estimated by this approach are plotted in **Figure 5**c and **Figure 5**d, respectively, together with the corresponding rates calculated from the experimental data. In both the nonstacked and stacked cases, we observe an excellent agreement between the delocalized dipole approach and the experimental data.

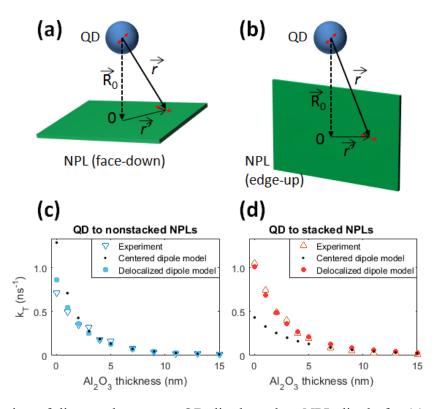


Figure 5. Variation of distance between a QD dipole and an NPL dipole for (a) nonstacked and (b) stacked NPL orientation, depending on the position \vec{r}' of the NPL dipole state. (c) Experimental rates of FRET to the nonstacked NPL monolayer (blue down triangle) compared to those estimated by two different models based on Förster's theory: center-to-center distance approach (small black dots) and delocalized dipole approach (large blue dots). (d) Experimental rates of FRET to the stacked NPL monolayer (orange up triangle) compared to the those estimated by center-to-center distance approach (small black dots) and delocalized dipole approach (large red dots). The delocalized dipole approach shows an excellent agreement with the experimental data whereas the centered dipole approach yields increasing discrepancy as the spacer thickness is diminishing.

To compare the predictions of this model with those of a conventional center-to-center distance approach, we also plotted the estimated FRET rates assuming the dipole states in the NPLs are centered in the NPLs (**Figure 5**c and **Figure 5**d; black dots). It is clearly seen that the

FRET rates calculated using the center-to-center distances do not agree with the experiment for small spacer thicknesses. The centered dipole approach overshoots the experimentally measured FRET rates for the nonstacked NPL monolayer and underestimates them for the stacked one progressively with decreasing spacer thickness in few nm's range, with this discrepancy maximized in the no spacer case. It is, however, worth noting that as the donor-acceptor separation increases, the estimations of both models converge to and agree well with the experimental FRET rates. This is the expected behavior since for large enough separations, the donor and acceptor can be approximated as point dipoles located at the donor and acceptor centers.

In conclusion, we proposed and demonstrated that controlled orientation of self-assembled NPL monolayers can be used to modify and control the strength of energy transfer via tuning of dipole-dipole interaction. We deposited NPLs in a desired orientation of either face-down or edge-up only and as a full monolayer over areas as large as 20 cm^2 using a liquid-air self-assembly technique. We showed that the FRET performance of the films substantially differ in each orientation. FRET from QDs to a monolayer of edge-up NPLs is about 50% stronger than to the face-down ones, whereas the distance dependence of their FRET rates is very similar and goes by $\sim d^4$ in both cases as expected for a plane of acceptors. The enhancement of FRET with stacking can be explained by the stronger dipole-dipole coupling and higher packing density. Our approach utilizing Förster theory and taking dipole state delocalization as well as different dipole-dipole interaction of QDs with nonstacked and stacked NPLs into account can successfully estimate the FRET rates from the QDs to the nonstacked and stacked NPL monolayers. Our study reveals a tool to use dipole interaction of NPLs with other NCs as an

additional degree of freedom for tuning the strength of FRET and sheds further light into the orientation-dependent optical properties of anisotropic colloidal semiconductor NPLs.

Methods

Synthesis of CdSe NPLs. CdSe NPLs having 4 monolayers (ML) of atomic thickness were synthesized using a previously reported recipe with slight modifications.³⁰ Initially, 340 mg of cadmium myristate and 24 mg of selenium (Se) in 30 mL of ODE were degassed and stirred at 95 °C under vacuum for an hour. Afterwards, the temperature was set to 240 °C and the vacuum was broken at 100 °C using argon gas. As the temperature reached about 195 °C, the color of solution became bright yellowish and 120 mg of cadmium acetate dihydrate (Cd(OAc)₂·2H₂O) was introduced swiftly into the reaction solution. After 10 min of growth of NPLs at 240 °C, the reaction was stopped with the injection of 1 mL of oleic acid (OA) and the temperature of the solution was cooled down to room temperature using a water bath. Subsequently, the resulting solution was centrifuged for 5 min at 6,000 rpm and the supernatant was removed into another centrifuge tube. After adding of ethanol into the supernatant solution until it became turbid, the solution was centrifuged again at 6,000 rpm for 10 min, and finally the precipitate of 4ML CdSe NPLs was dispersed in hexane.

Synthesis of CdZnS/ZnS core-graded shell QDs. The synthesis of blue-emitting QDs was performed according to the procedure in the literature with slight modifications.³¹ 1 mmol CdO, 10 mmol Zn acetate and 7 mL of OA were loaded into a 100 mL three-neck flask and stirred around 1 hour at 115 °C under vacuum condition. Then, 15 mL of ODE was added to the mixture and further degassed for about half an hour. Under Ar atmosphere, the reaction mixture was heated up to 300 °C. At this temperature, the first sulfur solution was quickly injected (1.6 mmol S dissolved in 2.4 mL ODE at 100 °C). After 12 min, 5 mL of 0.8 M sulfur precursor (4.8

mmol S dissolved in 6 mL OA at 140 °C) was injected at a rate of 0.5 mL/h. 1 hour later, remaining 1 mL of sulfur solution was injected with the same rate for the further growth of ZnS shell growth. When the reaction completed, the mixture cooled down to room temperature in water bath. For the purification step, QDs were cleaned a few times with isopropanol/ethanol mixture at 10,000 rpm and finally redispersed in toluene.

PL decay measurements. A FluoTime 200 Time-Resolved Spectrometer with a temporal resolution of 4 ps was used to measure the PL decays of only-QD and QD-NPL hybrid films at the QD emission peak of ~460 nm. The excitation laser has a wavelength of 375 nm, a pulse width of ~200 ps, a pulse repetition rate of 2.5 MHz and a spot size of ~100 μ m. The PL decays were fit to multiexponential decays $\sum_i A_i e^{-t/\tau_i}$ convolved with the instrument response function. The amplitude-averaged lifetimes were calculated as $\tau_{avg} = \sum_i (A_i \tau_i) / \sum_i A_i$.

ASSOCIATED CONTENT

Supporting Information. Photographs of the self-assembly experimental setup and thermal oxide wafers deposited with NPLs under UV-light. Additional SEM images of nonstacked and stacked NPL monolayer films. Derivation of the position-dependent average dipole-dipole interaction coefficient for QDs and nonstacked/stacked NPLs. PL decay fitting parameters. The following files are available free of charge.

brief description (file type, i.e., PDF)

brief description (file type, i.e., PDF)

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ACKNOWLEDGMENT

The authors acknowledge the financial support from the Singapore National Research Foundation under the program of NRF-NRFI2016-08 and in part from TUBITAK 115E679. H. V. Demir also gratefully acknowledges support from TUBA. O. Erdem, K. Gungor, I. Tanriover, M. Sak and Y. Kelestemur acknowledge TUBITAK for their financial support through BIDEB program.

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